

MBD5057-H20X Planar Tunnel Diode



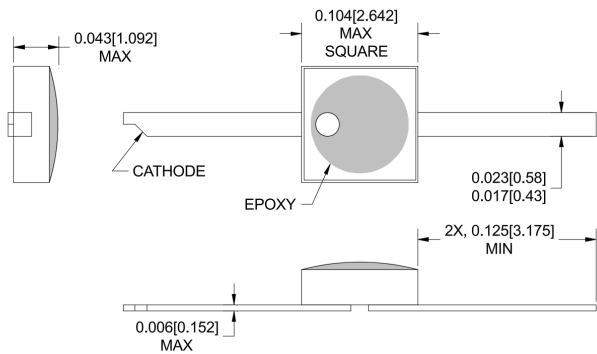
Technical Characteristics

- Rugged Germanium Planar Construction
- Excellent Temperature Stability
- No DC Bias Required
- Wide Video Bandwidth

EclipseMDI MBD5057-H20X, is a zero-bias, rugged Planar Tunnel Diode constructed with Germanium Planar. This tunnel diode exhibits excellent temperature stability, wide video bandwidth. The MBD5057 is also available in hermetic (H20) ceramic packages.

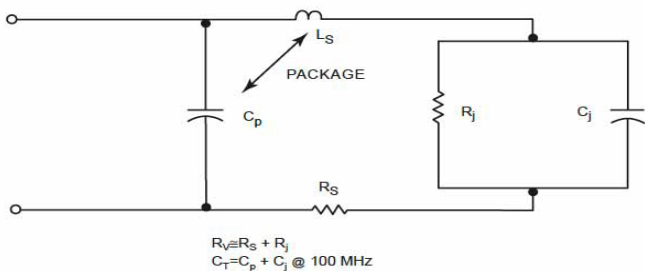
- Storage Temperature.....-65° to +125°C
- Operating Temperature.....-65° to +110°C
- Input Power Handling.....+17dBm CW or 3 ERG spike
- Soldering Temperature.....+160° C

H20X
(NON-HERMETIC)

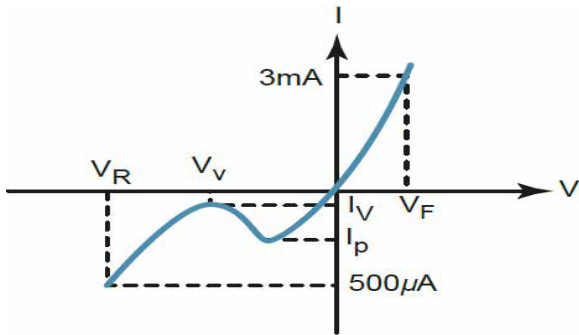


Ip		500		600	µA
Cj	Vr=Vv, f=100MHz			.30	pF
K[Y]	Pin=-20dBm RjLoad)=10K, f=10GHz		250		mV/mW
Rv			60		Ω Ohms
Ip/Iv		2.5			
Vr	If=500µA		400		mV
Vf	If=3mA			110	mV

Diode equivalent circuit



Back diode parameters



About EclipseMDI

ECLIPSE Microdevices is located in San Jose, California. ECLIPSE has been developing high performance analog semiconductors for use in wireless radio frequency (RF), microwave, and millimeter wave for commercial and industrial applications. ECLIPSE has formed a strategic alliances - with foundries that features leading state-of-the-art process technologies and with manufacturing facilities for high-volume production of innovative RFIC's.

Product Export Classification
ECCN: EAR 99 (unless otherwise specified)
HTS: 8541.10.0060

